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TECHNICAL DATA Motorola, Inc. 2001 INTEGRATED PRESSURE SENSOR 0 To 500 KPa

(0 To 72.5 Psi) 0.2 To 4.7 Volts Output PIN NUMBER NOTE: Pins 4, 5, And 6 Are Internal Device Connections. Do Not Connect To External Circuitry Or Ground. Pin 1 Is Noted By The Notch In The Lead. MPX5500D Apr 2th, 2024High-Performance/High-Reliability Semiconductor Discrete ...We Invite You To Review Our Complete Catalog Of Packaged And Unpackaged Semiconductor Diodes, Passive Elements, And Switches For Speci C RF And Microwave Applications. Products Include Silicon Varactors, PIN Diodes, Schottky Diodes, GaAs Schottky Diodes, Passive Elements, And PHEMT-based ... Is Testing Performed On A Sample Of The Lot To ... Jun 5th, 2024.

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